

High Voltage And High Speed Switching Transistors

TO-252

Features

- · Excellent Switching Times
- : t_{on} =1.1 μ S(Max.), t_{f} =0.7 μ S(Max.), at I_{C} =1.65A
- High Collector Voltage : $V_{CBO}=800V$

MAXIMUM RATINGS (Ta=25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Collector-Base Voltage		V_{CBO}	800	V	
Collector-Emitter Voltage		V_{CEO}	450	V	
Emitter-Base Volta	ge	V_{EBO}	9	V	
Collector Current	DC	$I_{\rm C}$	1.65	Λ	
Conector Current	Pulse		3.3	A	
Base Current		I_{B}	0.9	A	
Collector Power Dis (Tc=25°C	-	Pc	25	W	
Junction Temperatu	re	$T_{\rm j}$	150	$^{\circ}$ C	
Storage Temperatur	re Range	T_{stg}	-65~150	$^{\circ}$ C	

0.264(6.70) 0.256(6.50) 0.215(5.46) 0.022(0.56) 0.031(0.40) 0.031(0.80) 0.031(0.80) 0.043(1.10) 0.043(1.10) 0.055(1.40) 0.055

Dimensions in inches and (millimeters)

ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Emitter Cut-off Current	$I_{ m EBO}$	V_{EB} =9 V , I_{C} =0	-	-	10	μA
DC Current Gain	h _{FE} (1)Note	V_{CE} =2 V , I_{C} =1 A	19	_	36	
De current Gain	h _{FE} (2)	V_{CE} =2 V , I_{C} =1.65 A	5	_	25	
		I_{C} =0.5A, I_{B} =0.1A	-	-	0.5	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	$I_{C=1A}$ I_{B} =0.25 A	_	-	1	V
Saturday Voltage		$I_{\rm C}$ =1.65A $I_{\rm B}$ =0.5A	_	_	3	
Base-Emitter	V	I_{C} =0.5A, I_{B} =0.1A	_	_	1	V
Saturation Voltage	$V_{BE(sat)}$	$I_{C=1.65A}$ I_{B} =0.25 A	-	-	1.2	V
Collector Output Capacitance	C_{ob}	V_{CB} =10V, f=0.1MHz	_	21	I	рF
Transition Frequency	$ m f_{T}$	V_{CE} =10V, I_{C} =0.1A	4	_	ı	MHz
Turn-On Time	t _{on}	$100\mu S$ 1	-	-	1.1	μS
Storage Time	$t_{ m stg}$	\overline{I}_{B2} \overline{I}_{B2} \overline{I}_{B2} \overline{I}_{B2}	-	-	4.0	μS
Fall Time	t_{f}	I_{B1} = I_{B2} = 0.2A V_{CC} =125V DUTY CYCLE \leq 2%	_	_	0.7	μS

CLASSIFICATION OF $h_{\text{FE}(1)}$

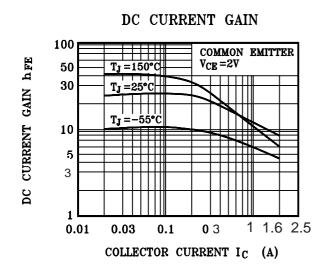
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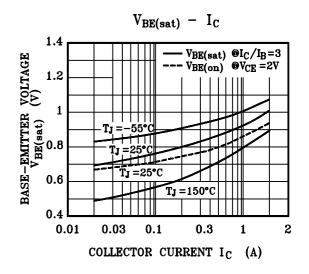
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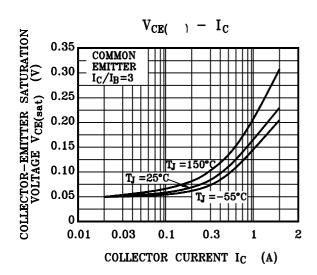


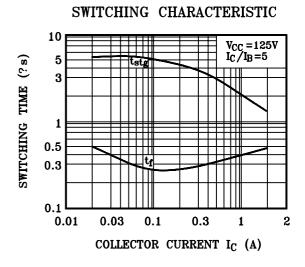
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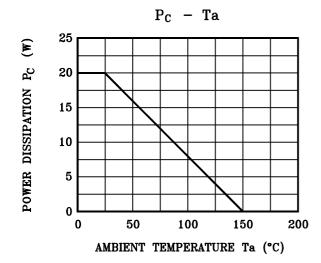
Typical Characteristics

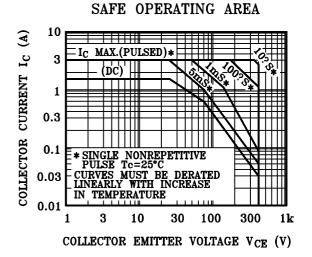












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